

MOSFET – Power, N-Channel, Dual EFCP

12 V, 6 A, 29.5 m Ω

EFC4627R

Features

- 2.5 V Drive
- Protection Diode In
- Common-Drain Type
- This Device is Pb–Free, Halogen Free/BFR Free and is RoHS Compliant

Applications

• Lithium-ion Battery Charging and Discharging Switch

Specifications

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V _{SSS}		12	V
Gate to Source Voltage	V _{GSS}		±10	V
Source Current (DC)	I _S		6	Α
Source Current (Pulse)	I _{SP}	PW ≤ 10 μs, Duty Cycle ≤1%	60	Α
Total Dissipation	P _T	When mounted on ceramic substrate (5000 mm ² x 0.8 mm)	1.4	W
Junction Temperature	TJ		150	°C
Storage Temperature	T _{stg}		– 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (5000 mm ² x 0.8 mm)	$R_{ heta JA}$	84	V



CSP4 1.01x1.01 CASE 568AK

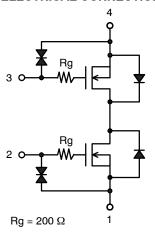
MARKING DIAGRAM



C = Specific Device CodeY = Year of Production

M = Assembly Operation MonthZZ = Assembly Lot Number

ELECTRICAL CONNECTION



ORDERING INFORMATION

Device	Package	Shipping [†]
EFC4627R-TR	CSP4 (Pb-Free and Halogen Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V _{(BR)SSS}	I _S = 1 mA, V _{GS} = 0 V	Test Circuit 1	12	-	_	V
Zero-Gate Voltage Source Current	I _{SSS}	V _{SS} = 10 V, V _{GS} = 0 V	Test Circuit 1	-	-	1	μΑ
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{SS} = 0 \text{ V}$	Test Circuit 2	-	-	±1	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{SS} = 6 V, I _S = 1 mA	Test Circuit 3	0.5	-	1.3	V
Forward Transconductance	9 _{FS}	V _{SS} = 6 V, I _S = 2 A	Test Circuit 4	-	4.8	_	S
Static Source to Source On-State Resistance	R _{SS} (on)1	I _S = 2 A, V _{GS} = 4.5 V	Test Circuit 5	18.5	23.9	29.5	mΩ
	R _{SS} (on)2	I _S = 2 A, V _{GS} = 4.0 V	Test Circuit 5	19.7	25.4	31.3	mΩ
	R _{SS} (on)3	I _S = 2 A, V _{GS} = 3.8 V	Test Circuit 5	20.3	26.1	32.3	mΩ
	R _{SS} (on)4	I _S = 2 A, V _{GS} = 3.1 V	Test Circuit 5	23.5	30.3	39.0	mΩ
	R _{SS} (on)5	I _S = 2 A, V _{GS} = 2.5 V	Test Circuit 5	29.3	37.7	50.5	mΩ
Turn-On Delay Time	t _d (on)	$V_{SS} = 6 \text{ V}, V_{GS} = 4.5 \text{ V},$	Test Circuit 6	-	75	_	ns
Rise Time	t _r	I _S = 2 A		-	740	_	ns
Turn-Off Delay Time	t _d (off)			-	2340	_	ns
Fall Time	t _f			-	2320	_	ns
Total Gate Charge	Qg	V _{SS} = 6 V, V _{GS} = 4.5 V, I _S = 6 A	Test Circuit 7	-	13.4	-	nC
Forward Source to Source Voltage	V _{F(S-S)}	I _S = 3 A, V _{GS} = 0 V	Test Circuit 8	-	0.76	_	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Test Circuits are Example of Measuring FET1 Side.

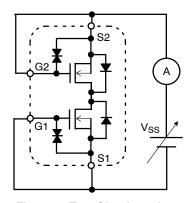
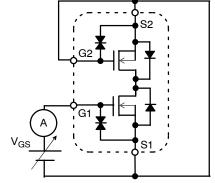


Figure 1. Test Circuit 1 - I_{SSS}



When FET1 is measured, Gate and Source of FET2 are short-circuited.

Figure 2. Test Circuit 2 - I_{GSS}

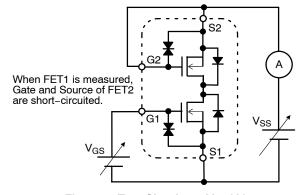


Figure 3. Test Circuit 3 - V_{GS}(th)

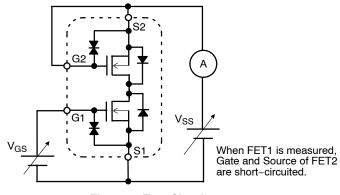
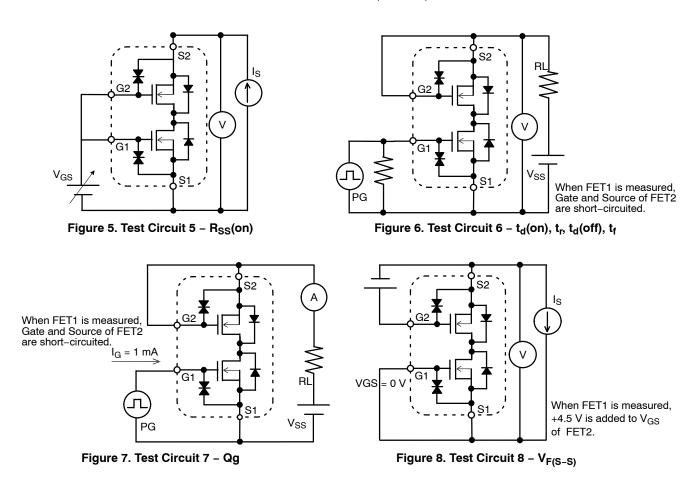


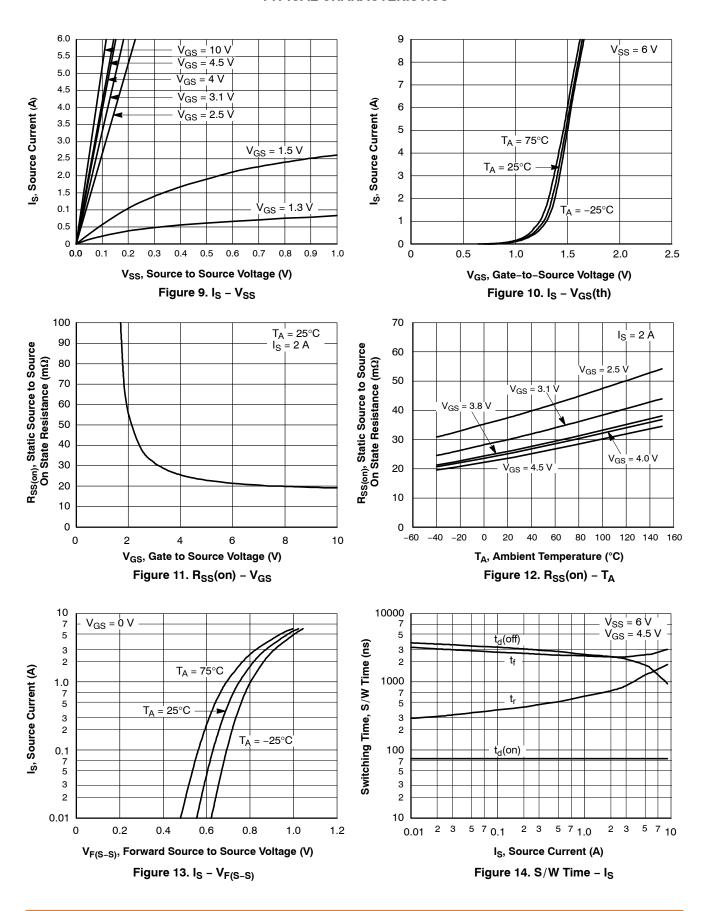
Figure 4. Test Circuit 4 - g_{FS}

TEST CIRCUITS (continued)

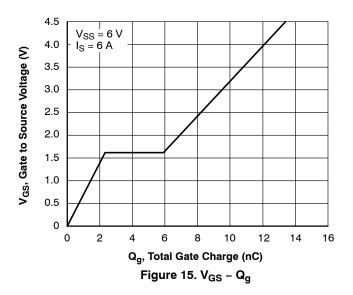


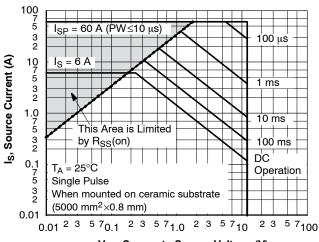
NOTE: When FET2 is measured, the position of FET1 and FET2 is switched.

TYPICAL CHARACTERISTICS

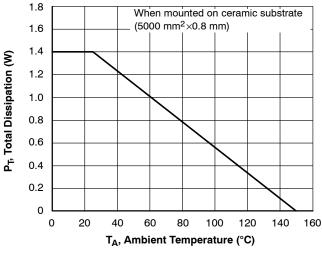


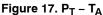
TYPICAL CHARACTERISTICS (continued)





V_{SS}, Source to Source Voltage (V) Figure 16. SOA





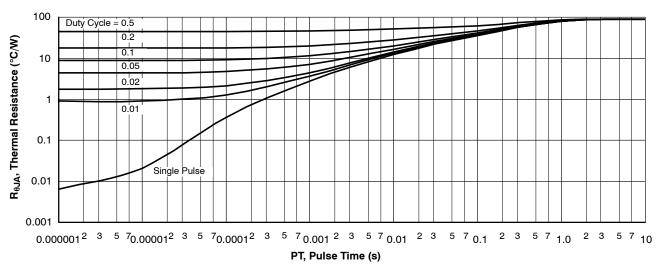


Figure 18. $R_{\theta JA}$ – Pulse Time

PACKAGE DIMENSION

EFC4627R-TR (Unit: mm)

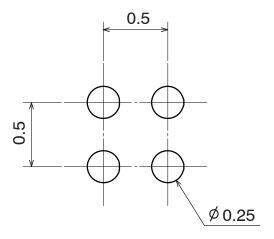


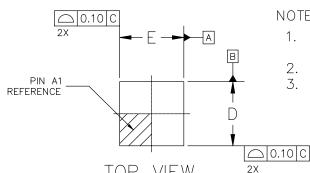
Figure 19. Recommended Soldering Footprint

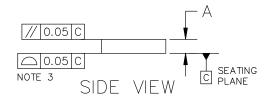




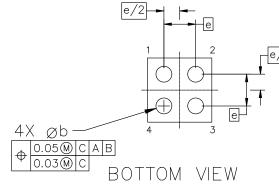
WLCSP4, 1.01x1.01x0.20, 0.50P CASE 568AK **ISSUE C**

DATE 05 NOV 2024





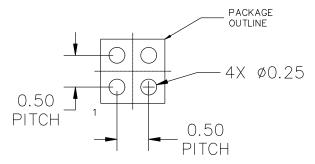
TOP VIEW



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- COPLANARITY APPLIES TO THE SPHERICAL CROWNS OF THE SOLDER BALLS.

MILLIMETERS					
DIM	MIN	NOM	MAX		
А	0.18	0.20	0.22		
b	0.22	0.25	0.28		
D	0.99	1.01	1.11		
Е	0.99	1.01	1.11		
е	0.50 BSC				



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques References manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON78060F	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	WLCSP4, 1.01x1.01x0.20, 0.50P		PAGE 1 OF 1	

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves brisefin and of 160 m are trademarked so defined values of services and of the confined values and of the values of the confined values and of the values of the confined values and of the values of the special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales